FORM PTO-1449 U.S. DEPARTME' 'OF COMMERCE Atty Docket: ADACHI P163USP2 Examiner: John . ffmann PATENT AND TRADEMARK OFFICE (Rev.2-32) Group: 1731 INFORMATION DISCLOSURE Applicant: Akira IKUSHIMA, Kazuya SAITO, Takashi STATEMENT BY APPLICANT MIURA and Shogo NASUDA (Use several sheets if necessary) U.S. PATENT DOCUMENTS Examiner Document Sub-Filing Date, <u>Vumber</u> Class Name if Appropriate <u>Jun. 1977</u> 4,028,080 Di Vita 4,157,253 Jun. 1979 <u>Hemal/Ist</u> 4,182,664 Jan. 1980 Maklad 5,267,343 Nov. 1993 Lyons 5,620,496 Apr. 1997 Erdogan 5.983,673 Nov. 1999 <u>Urano</u> 6,058,739 May 2000 Morton 5,478,371 Dec. 26, 1995 Lemaire et al FOREIGN PATENT DOCUMENTS Examiner Document Sub-Translation Initials/ Number Country Class Nο 0 687 924 A1 Dec. 20, 1995 **EPO** 2808457 Aug. 1974 Germany 4-342427 4-342436 Jun. 7, 1994 6-199539 4 Japan 52-94657 Nov. 1993 Japan Not considered in Parent 54-134721 Oct. 1979 Japan 57-188423 Nov. 1982 Japan 57-191247 Nov. 25, 1982 Japan 60-200204 Oct. 9, 1985 <u>Japan</u> 61-45201 Mar. 5, 1986 <u>Japan</u> 05-288942 Nov. 5, 1993 <u>Japan</u> 09-230048 Sep. 5, 1997 Japan 01-316445 Dec. 2, 1998 Japan 11-029335 Feb. 2, 1999 <u>Japan</u> OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.) "Thermal Annealing of Defects Indosed by Art Excimer Laser Irradiation in a SiO<sub>2</sub>"; Japanese Society of Applied Physics, Catalog No. AP 90110-02 (English Translation) ROTHSCHILED, Mordechai, Daniel J. EHRLICH and David C. SHAVER, "Eximer Laser Induced Damage in Fused Silica", Microelectronic Engineering 11, 1990, pp. 167-172 "Temperature Dependence of the E1 Center Creation in Silica Glasses", Physica Status Soiidi (b), vol. 147,

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